

UNISONIC TECHNOLOGIES CO., LTD

# UT4410

# N-CHANNEL 30-V (D-S) MOSFET

## DESCRIPTION

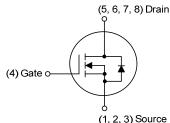
As advanced N-channel logic level enhancement MOSFET, the **UT4410** is produced using UTC's high cell density, DMOS trench technology. which has been specially tailored to minimize the on-resistance and maintain low gate charge for superior switching performance.

These devices can be particularly suited for such low voltage applications: cellular phone and notebook computer power management and other battery powered circuits where high-side switching and low in-line power loss are needed in a very small outline surface mount package.

#### FEATURES

- \*  $R_{DS(ON)}$  < 18 m $\Omega$  @ V<sub>GS</sub>=10V, I<sub>D</sub>=10A
- \*  $R_{DS(ON)}$  < 20 m $\Omega$  @  $V_{GS}$ =4.5V,  $I_{D}$ =8A
- \* Ultra low gate charge (typical 11 nC)
- \* Low reverse transfer capacitance (  $C_{\text{RSS}}$  = typical 35 pF )
- \* Fast switching capability
- \* Avalanche energy specified
- \* Improved dv/dt capability, high ruggedness

#### SYMBOL

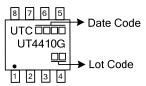


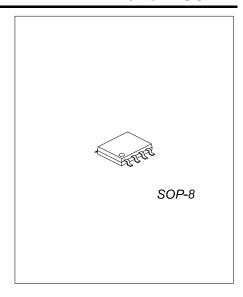
ORDERING INFORMATION

	Daakaga	Pin Assignment								Deaking	
Ordering Number	Package	1	2	3	4	5	6	7	8	Packing	
UT4410G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel	
Note: Pin Assignment: G: Gate D: Dra	in S: Source										

UT4410<u>G-S08-R</u> (1) Packing Type (2) Package Type (3) Green Package (3) Green Package (3) G: Halogen Free and Lead Free

## MARKING





Power MOSFET

#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> =25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V <sub>DSS</sub>	30	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	11.6	А
Pulsed Drain Current	I <sub>DM</sub>	46.4	А
Power Dissipation	PD	3.6	W
Junction Temperature	TJ	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### THERMAL DATA

PARAMETER S	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ <sub>JA</sub>	60	°C/W

Note: The device mounted on 1in<sup>2</sup> FR4 board with 2 oz copper

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C, unless otherwise specified)

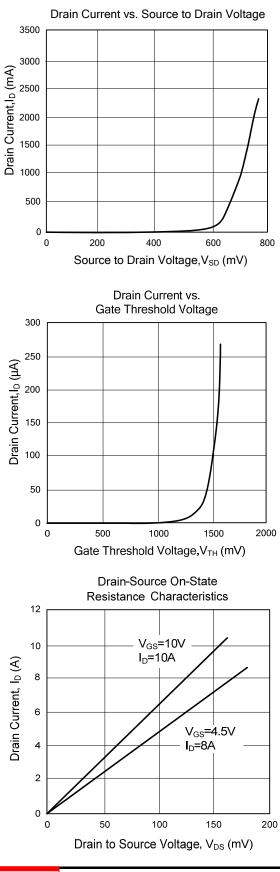
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS					- -	
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	1			μA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V			±100	nA
ON CHARACTERISTICS						
Gate-Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250µA	1.3	1.6	3.0	V
Static Drain–Source On–Resistance(Note)	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A		12	18	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =8A		17	20	mΩ
On-State Drain Current(Note)	I <sub>D(ON)</sub>	V <sub>DS</sub> = 5V, V <sub>GS</sub> =10V	20			Α
DYNAMIC PARAMETERS						
Input Capacitance	CISS			700	800	рF
Output Capacitance	Coss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHz		120		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			35		pF
Gate Resistance	R <sub>G</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =0V, f=1.0MHz		0.9		Ω
SWITCHING PARAMETERS			•		i	
Turn-ON Delay Time	t <sub>D(ON)</sub>			14	32	ns
Turn-ON Rise Time	t <sub>R</sub>	$V_{DD}$ =25V, $I_D$ =1A, $R_L$ =25 $\Omega$		12	64	ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	$V_{GEN}$ =10V, $R_G$ =6 $\Omega$		43	280	ns
Turn-OFF Fall-Time	t <sub>F</sub>			4	192	ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DS</sub> =15V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		11	15	nC
Total Gate Charge	Q <sub>GT</sub>			20	26	nC
Gate Source Charge	$Q_{GS}$	V <sub>DS</sub> =15V, V <sub>GS</sub> =10V, I <sub>D</sub> =10A		5		nC
Gate Drain Charge	$Q_{GD}$			4.9		nC
SOURCE- DRAIN DIODE RATINGS AND C	HARACTER	ISTICS		-		
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =2.3 A,V <sub>GS</sub> =0V		0.7	1.1	V

Note: Pulse test; pulse width  $\leq$  300us, duty cycle $\leq$  2%

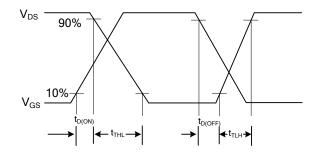


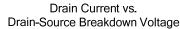
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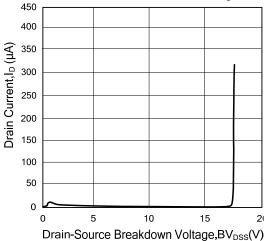
## TYPICAL CHARACTERISTICS



Switching Time Waveforms







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